

ON Semiconductor®

FDD86380-F085

N-Channel PowerTrench[®] MOSFET 80 V, 50 A, 13.5 m Ω

Features

- Typical $R_{DS(on)}$ = 11.2 m Ω at V_{GS} = 10V, I_D = 50 A
- Typical $Q_{g(tot)}$ = 20 nC at V_{GS} = 10V, I_D = 50 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems

ROHS



Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		80	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50		
	Pulsed Drain Current	T _C = 25°C	See Figure 4	— A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	17.6	mJ	
P _D	Power Dissipation		75	W	
	Derate Above 25°C		0.5	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.0	°C/W	
R _{0JA}	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W	

G

S

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}C$, $L = 22\mu$ H, $I_{AS} = 40A$, $V_{DD} = 80V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD86380	FDD86380-F085	D-PAK(TO-252)	13"	16mm	2500units

D

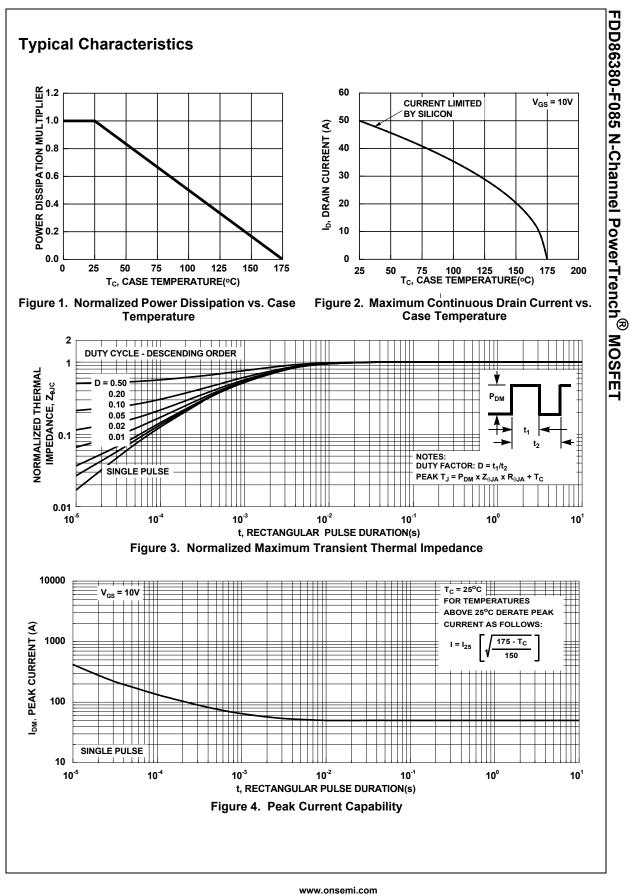
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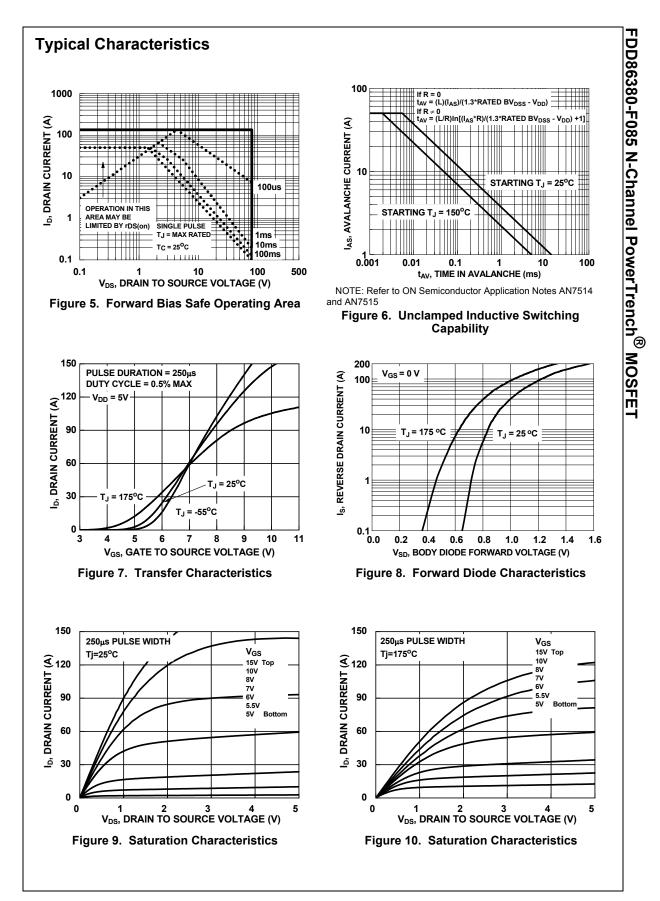
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D-PAK

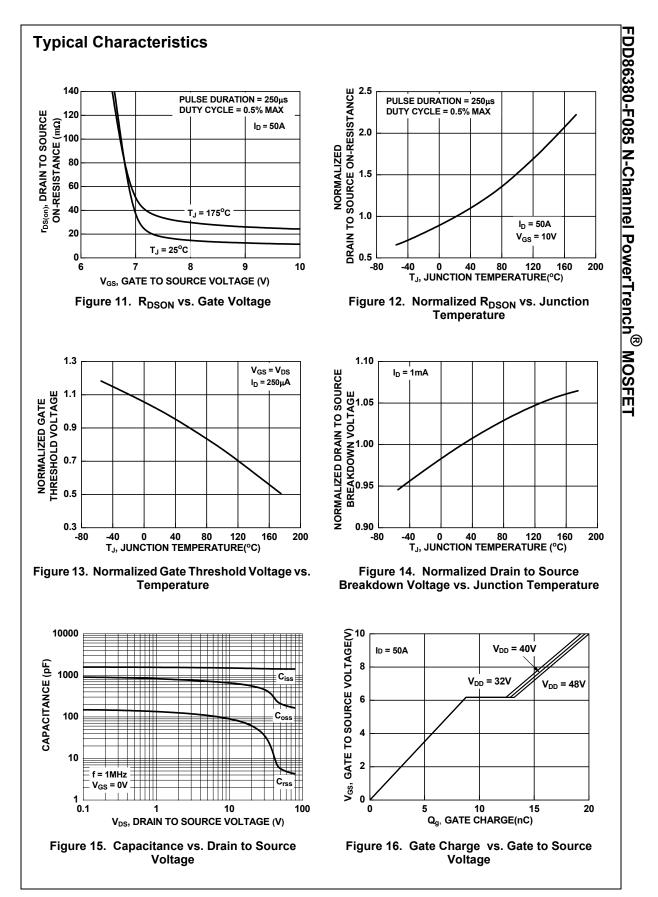
(TO-252)

Symbol	Parameter	Test Conditions		Тур.	Max.	Units
Off Cha	racteristics					r
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	80	-	-	V
	Drain-to-Source Leakage Current	V_{DS} =80V, T_{J} =25°C	-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$ $T_J = 175^{\circ}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V_{GS} = ±20V	-	-	±100	nA
On Cha	racteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	2	3	4	V
_	Drain to Source On Resistance	$I_{\rm D} = 50$ A, $T_{\rm J} = 25^{\rm o}$ C	-	11.2	13.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	V_{GS} = 10V T_{J} = 175°C (Note 4)	-	24.9	30	mΩ
Dynami	ic Characteristics					
C _{iss}	Input Capacitance	y' = 40y' y' = 0y'	-	1440	-	pF
C _{oss}	Output Capacitance	─V _{DS} = 40V, V _{GS} = 0V, f = 1MHz	-	311	-	pF
C _{rss}	Reverse Transfer Capacitance		-	15	-	pF
R _g	Gate Resistance	V _{GS} = 0.5V, f = 1MHz	-	2	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 64V$	-	20	30	nC
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V $I_D = 50A$	-	3	-	nC
Q _{gs}	Gate-to-Source Gate Charge		-	9	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge		-	4	-	nC
Switchi	ng Characteristics		-	-	38	ns
t _{d(on)}	Turn-On Delay		-	12	-	ns
t _r	Rise Time	V _{DD} = 40V, I _D = 50A,	-	13	-	ns
t _{d(off)}	Turn-Off Delay	$V_{GS} = 10V, R_{GEN} = 6\Omega$	-	15	-	ns
t _f	Fall Time		-	6	-	ns
t _{off}	Turn-Off Time		-	-	30	ns
Drain-S	ource Diode Characteristics					
	Source-to-Drain Diode Voltage	$I_{SD} = 50A, V_{GS} = 0V$	-	-	1.25	V
V _{SD}	-	$I_{SD} = 25A, V_{GS} = 0V$	-	-	1.2	V
V _{SD}			-	36	54	ns
V _{SD} t _{rr} Q _{rr}	Reverse-Recovery Time Reverse-Recovery Charge	V _{DD} = 64V, I _F = 50A, dl _{SD} /dt = 100A/μs		24	36	nC





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